

Amplified Very Low Pressure Sensors

AMPLIFIED Pressure Sensors



Features

- 0.25 and 0.50 In H₂O Pressure Ranges
- Ratiometric 4V Output
- Temperature Compensated
- Calibrated Zero and Span

Applications

- Medical Breathing
- HVAC

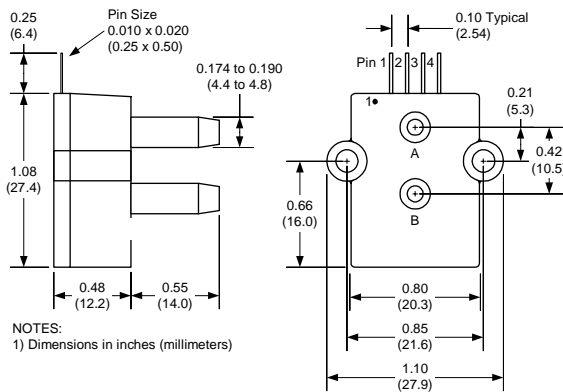
General Description (generic product)

The Amplified line of low pressure sensors is based upon a proprietary technology to reduce all output offset or common mode errors. This model provides a ratiometric 4-volt output with superior output offset characteristics. Output offset errors due to change in temperature, stability to warm-up, stability to long time period, and position sensitivity are all significantly reduced when compared to conventional compensation methods. In addition the sensor utilizes a silicon, micromachined, stress concentration enhanced structure to provide a very linear output to measured pressure.

These calibrated and temperature compensated sensors give an accurate and stable output over a wide temperature range. This series is intended for use with non-corrosive, non-ionic working fluids such as air, dry gases and the like.

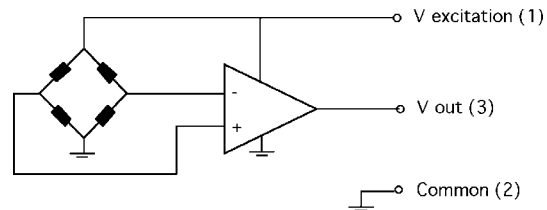
The output of the device is ratiometric to the supply voltage over a supply voltage range of 4.5 to 5.5 volts.

Physical Dimensions



- pin 1: Vsupply**
- pin 2: Common**
- pin 3: Voutput**
- pin 4: do not connect**

Equivalent Circuit



Pressure Sensor Ratings

Supply Voltage, Vs	+4.5 to +5.5 Vdc
Common-mode pressure	-10 to +10 psig
Lead Temperature, max (soldering 2-4 sec.)	250°C

Environmental Specifications

Temperature Ranges	
Compensated	5 to 50° C
Operating	-25 to 85° C
Storage	-40 to 125° C
Humidity Limits	0 to 95% RH (non condensing)

Performance Characteristics for: 0.25 INCH-D-4V

Parameter, NOTE 1	Minimum	Nominal	Maximum	Units
Operating Range, differential pressure		±0.25		"H ₂ O
Output Span, NOTE 5	±1.80	±20	±2.20	volt
Offset Voltage @ zero differential pressure	2.00	2.25	2.50	volt
Offset Temperature Shift (5°C-50°C), NOTE 2			±50	mvolt
Offset Warm-up Shift, NOTE 3		±20	±50	mvolt
Offset Position Sensitivity (±1g)		±40	±100	mvolt
Offset Long Term Drift (one year)		±20	±50	mvolt
Linearity, hysteresis error, NOTE 4		0.05	0.25	%fs
Span Shift (5°C-50°C), NOTE 2			±4	%span

Performance Characteristics for: 0.5 INCH-G-4V

Parameter, NOTE 1	Minimum	Nominal	Maximum	Units
Operating Range, gage pressure		0.5		"H ₂ O
Output Span, NOTE 5	3.80	4.0	4.20	volt
Offset Voltage @ zero gage pressure	0.10	0.25	0.40	volt
Offset Temperature Shift (5°C-50°C), NOTE 2			±50	mvolt
Offset Warm-up Shift, NOTE 3		±20	±50	mvolt
Offset Position Sensitivity (±1g)		±40	±100	mvolt
Offset Long Term Drift (one year)		±20	±50	mvolt
Linearity, hysteresis error, NOTE 4		0.05	0.25	%fs
Span Shift (5°C-50°C), NOTE 2			±4	%span

Specification Notes

NOTE 1: ALL PARAMETERS ARE MEASURED AT 5.0 VOLT EXCITATION, FOR THE NOMINAL FULL SCALE PRESSURE AND ROOM TEMPERATURE UNLESS OTHERWISE SPECIFIED. **PRESSURE MEASUREMENTS ARE WITH POSITIVE PRESSURE APPLIED TO PORT B.**

NOTE 2: SHIFT IS RELATIVE TO 25°C.

NOTE 3: SHIFT IS WITHIN THE FIRST HOUR OF EXCITATION APPLIED TO THE DEVICE.

NOTE 4: MEASURED AT ONE-HALF FULL SCALE RATED PRESSURE USING BEST STRAIGHT LINE CURVE FIT.

NOTE 5: THE VOLTAGE ADDED TO THE OFFSET VOLTAGE AT FULL SCALE PRESSURE. NOMINALLY THE OUTPUT VOLTAGE RANGE IS 0.25 TO 4.25 VOLTS FOR MINUS TO PLUS FULL SCALE PRESSURE.

All Sensors reserves the right to make changes to any products herein. All Sensors does not assume any liability arising out of the application or use of any product or circuit described herein, neither does it convey any license under its patent rights nor the rights of others.

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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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